

HIGH RELIABILITY HYBRID RADIATION TOLERANT DC-DC CONVERTERS

DESCRIPTION

The SVTR series of high reliability DC-DC converters is operable over the full military temperature range (-55 °C to +125 °C) with no power derating. Paramount to the SVTR series is a magnetic feedback circuit that is radiation immune. Operating at a nominal fixed frequency of 500 kHz, these regulated, isolated units utilize wellcontrolled undervoltage lockout circuitry to eliminate slow start-up problems.

The SVTR series is specifically designed for the harsh radiation environment of space applications. Performance is guaranteed through the use of hardened semiconductor components, radiation lot acceptance testing (RLAT) of non-hardened components and analysis. The SVTR series has been characterized for Total Ionizing Dose (TID) performance including Enhanced Low Dose Rate Sensitivity (ELDRS) and for Single Event Effects (SEE) according to VPT's DLA approved Radiation Hardness Assurance (RHA) plan per MIL-PRF-38534, Appendix G. Characterization is performed at both the component level and at the SVTR series hybrid converter level.

These converters are designed and manufactured in a facility qualified to ISO9001 and certified to MIL-PRF-38534 Class H and Class K and MIL-STD-883.

This product may incorporate one or more of the following U.S. patents:

5,784,266 5,790,389 5,963,438 5,999,433 6,005,780 6,084,792 6,118,673

FEATURES

- Guaranteed TID Performance to 30 krad(Si) including ELDRS, per VPT's RHA plan specified per MIL-PRF-38534, Appendix G, Level P with 2X margin.
- Characterized to 44 MeV-cm²/mg with minor transients only; no dropouts, shutdowns, latch up or burn out.
- High Reliability
- Very Low Output Noise
- Wide Input Voltage Range: 15 to 50 Volts per MIL-STD-704
- Up to 40 Watts Output Power
- Output Voltage Trim Up +10%
- Radiation Immune Magnetic Feedback Circuit
- NO Use of Optoisolators
- Undervoltage Lockout
- Current Limit and Short Circuit Protection
- High Input Transient Voltage: 80 Volts for 1 sec per MIL-STD-704A
- Precision Seam Seal Hermetic Package
- High Power Density: > 40 W/in³
- Custom Modified Versions May Be Available
- Additional Environmental Screening Available
- Meets MIL-STD-461 Revisions C, D, E and F EMC Requirements When Used With VPT's EMI Filters
- Flanged and Non-flanged Versions Available.
- MIL-PRF-38534 Element Evaluated Components
- Worst Case analysis, Stress, Radiation, and Reliability reports available¹

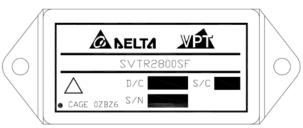


Figure 1 – SVTR2800S / SVTR2800SF DC-DC Converter (Exact marking may differ from that shown)

¹Subject to all export restrictions and export regulations including but not limited to the Export Administration and Foreign Assets Control Regulations. Further restrictions may apply contact VPT for details.



SPECIFICATIONS (T_{CASE} = -55°C to +125°C, V_{IN} = +28V \pm 5%, Full Load, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS			
Input Voltage (Continuous)	50 V_{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}C$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams
ESD Rating per MIL-PRF-38534	3A		

Deveryoter		Cond	1:4: o m o ⁵	S	VTR283R	3S	5	SVTR2805	S	Units
Parameter		Conditions⁵		Min	Тур	Мах	Min	Тур	Мах	Units
STATIC										
INPUT		Continuous		15	28	50	15	28	50	V
Voltage ⁴		Transient, 1 sec		-	-	80	-	-	80	V
Quantant		Inhibited		-	4	6	-	4	6	mA
Current	Current			-	50	90	-	55	90	mA
Dipple Current		Full Load, 20	Hz to 10MHz	-	20	50	-	30	50	mA_{p-p}
Ripple Current			End-of-Life	-	-	70	-	-	70	mA_{p-p}
Inhibit Pin Input ^₄				0	-	1.5	0	-	1.5	V
Inhibit Pin Open Circuit Voltage ⁴				9.0	11.0	13.0	9.0	11.0	13.0	V
UVLO Turn On				12.0	-	14.8	12.0	-	14.8	V
UVLO Turn Off ⁴				11.0	-	14.5	11.0	-	14.5	V
	V_{OUT}	T _{CASE} = 25°C	T _{CASE} = 25°C		3.30	3.35	4.95	5.00	5.05	V
OUTPUT Voltage	V_{OUT}	$T_{CASE} = -55^{\circ}C$	C to +125°C	3.20	3.30	3.40	4.875	5.00	5.125	V
vollago	V_{OUT}		End-of-Life	3.20	-	3.40	4.875	-	5.125	V
Power ³				0	-	20	0	-	30	W
Current ³	V _{OUT}			0	-	6.06	0	-	6.0	А
Ripple Voltage	V_{OUT}	Full Load, 20	Hz to 10MHz	-	25	50	-	20	50	mV_{p-p}
Line Regulation	V _{OUT}	V_{IN} = 15V to	50V	-	2	20	-	2	20	mV
Load Regulation	V_{OUT}	No Load to F	ull Load	-	2	50	-	2	50	mV
EFFICIENCY				65	70	-	72	78	-	%
		Overload ⁴		-	-	16	-	-	16	W
LOAD FAULT POWER DISSIPATION		Short Circuit		-	-	16	-	-	16	W
CAPACITIVE LOAD ⁴				-	-	1000	-	-	1000	μF
SWITCHING FREQUENCY				400	500	550	400	500	550	kHz
SYNC FREQUENCY RANG	E	$V_{H} - V_{L} = 5V,$	DC = 20-80%	500	-	600	500	-	600	kHz
ISOLATION		$500 V_{DC}$		100	-	-	100	-	-	MΩ
MTBF (MIL-HDBK-217F)		SF @ T _c = 5	5°C	-	752	-	-	752	-	kHrs



SPECIFICATIONS (T_{CASE} = -55°C to +125°C, V_{IN} = +28V ± 5%, Full Load, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS			
Input Voltage (Continuous)	50 V_{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, T _{CASE} = +125°C)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams
ESD Rating per MIL-PRF-38534	3A		

Parameter		Conditions ⁵	S	SVTR283R3S		SVTR2805S			Units
		Conditions	Min	Тур	Max	Min	Тур	Мах	Units
DYNAMIC									
Load Step Output Transient	V_{OUT}	Half Load to Full Load	-	180	500	-	170	500	тV _{РК}
Load Step Recovery ²			-	260	500	-	60	500	μSec
Line Step Output Transient ⁴	V_{OUT}	1/2 = 161/1 = 101/2	-	300	600	-	300	600	тV _{РК}
Line Step Recovery ^{2, 4}		$V_{IN} = 16V \text{ to } 40V$	-	300	500	-	300	500	μSec
Turn On Delay	V_{OUT}	$V_{IN} = 0V$ to 28V	-	10	20	-	10	20	mSec
Turn On Overshoot		V _{IN} – UV (U 20V	-	0	15	-	0	25	тV _{РК}

Notes: 1. Dependant on output voltage.

age. 2. Time for output voltage to settle within 1% of its nominal value.

3. Derate linearly to 0 at 135°C. 4. Verified by qualification testing.

5. End-of-Life performance includes aging and radiation degradation and is within standard limits except where noted.



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Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}C$)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams
ESD Rating per MIL-PRF-38534	3A		

Deveryoter		Cond	:4: 5	S	SVTR2812	S	S	SVTR2815	S	Units
Parameter		Conditions⁵		Min	Тур	Мах	Min	Тур	Мах	Units
STATIC										
INPUT	INPUT		Continuous		28	50	15	28	50	V
Voltage ⁴		Transient, 1 sec		-	-	80	-	-	80	V
Current		Inhibited		-	4	6	-	4	6	mA
Current		No Load		-	60	90	-	60	90	mA
Dinale Overent		Full Load, 20	Hz to 10MHz	-	30	50	-	30	50	mA _{p-p}
Ripple Current			End-of-Life	-	-	70	-	-	70	mA _{p-p}
Inhibit Pin Input ^₄				0	-	1.5	0	-	1.5	V
Inhibit Pin Open Circuit Voltage ⁴				9.0	11.0	13.0	9.0	11.0	13.0	V
UVLO Turn On				12.0	-	14.8	12.0	-	14.8	V
UVLO Turn Off⁴				11.0	-	14.5	11.0	-	14.5	V
	V _{OUT}	T _{CASE} = 25°C		11.88	12.0	12.12	14.85	15.0	15.15	V
OUTPUT Voltage	V_{OUT}	$T_{CASE} = -55^{\circ}C$	C to +125°C	11.70	12.0	12.30	14.625	15.0	15.375	V
vollage	V _{OUT}		End-of-Life	11.66	-	12.30	14.565	-	15.4	V
Power ³				0	-	40	0	-	40	W
Current ³	V _{OUT}			0	-	3.33	0	-	2.67	Α
Ripple Voltage	V _{OUT}	Full Load, 20	Hz to 10MHz	-	20	50	-	20	50	mV _{p-p}
Line Regulation	V _{OUT}	V_{IN} = 15V to 5	50V	-	2	20	-	2	20	mV
Load Regulation	V _{OUT}	No Load to F	ull Load	-	10	50	-	10	50	mV
EFFICIENCY				76	84	-	77	84	-	%
		Overload ⁴		-	-	14	-	-	14	W
LOAD FAULT POWER DISSIPATION		Short Circuit		-	-	14	-	-	14	W
CAPACITIVE LOAD ⁴				-	-	500	-	-	500	μF
SWITCHING FREQUENCY	SWITCHING FREQUENCY			400	500	550	400	500	550	kHz
SYNC FREQUENCY RANG	E	$V_H - V_L = 5V,$	DC = 20-80%	500	-	600	500	-	600	kHz
ISOLATION		500 V _{DC}		100	-	-	100	-	-	MΩ
MTBF (MIL-HDBK-217F)		SF @ T _c = 58	5°C	-	752	-	-	752	-	kHrs



SPECIFICATIONS (T_{CASE} = -55°C to +125°C, V_{IN} = +28V ± 5%, Full Load, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS			
Input Voltage (Continuous)	50 V_{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
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ESD Rating per MIL-PRF-38534	3A		

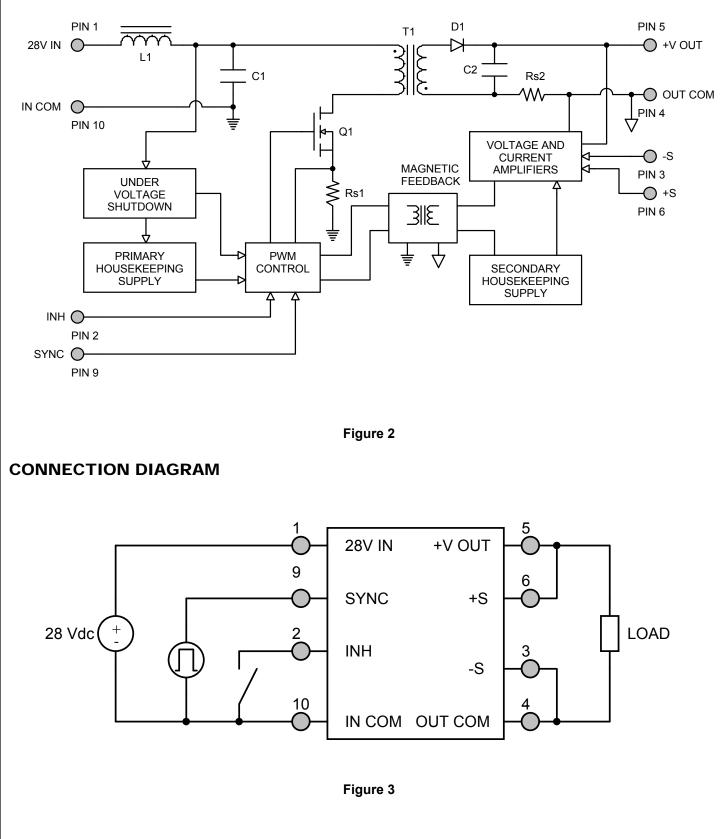
Parameter		Conditions ⁵	5	SVTR2812S		SVTR2815S			Units
		M		Тур	Max	Min	Тур	Мах	Units
DYNAMIC									
Load Step Output Transient	V _{OUT}	Half Load to Full Load	-	450	700	-	500	700	тV _{РК}
Load Step Recovery ²			-	200	500	-	150	500	μSec
Line Step Output Transient ⁴	V _{OUT}	V _{IN} = 16V to 40V	-	500	900	-	500	900	тV _{РК}
Line Step Recovery ^{2, 4}		$v_{\rm IN} = 16V \ 1040V$	-	300	500	-	300	500	μSec
Turn On Delay	V _{OUT}	$V_{\rm IN} = 0V$ to 28V	-	10	20	-	10	20	mSec
Turn On Overshoot		V _{IN} - UV (0 28V	-	0	50	-	0	50	тV _{РК}

Notes:1. Dependant on output voltage.
3. Derate linearly to 0 at 135°C.2. Time for output voltage to settle within 1% of its nominal value.
4. Verified by qualification testing.

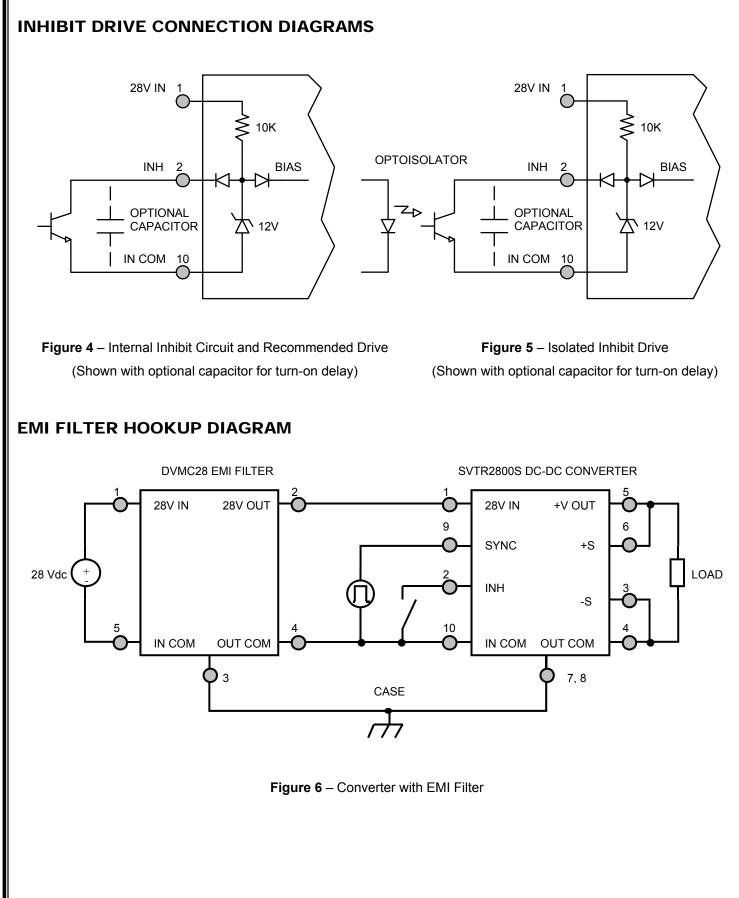
5. End-of-Life performance includes aging and radiation degradation and is within standard limits except where noted.





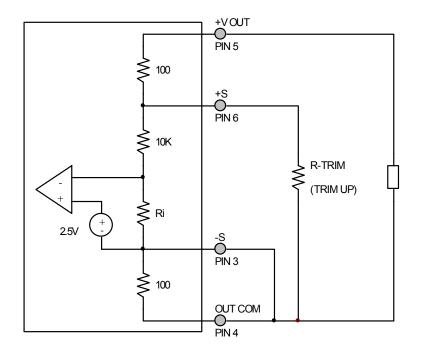








OUTPUT VOLTAGE TRIM



The output voltage can be trimmed up by connecting a resistor between the +S pin (PIN 6) and the OUT COM pin (PIN 4). The maximum trim range is +10%. The appropriate resistor values versus the output voltage are given in the trim table below. The -S pin should be connected to the OUT COM pin.

Figure 7 – Output Voltage Trim

SVTR2	83R3S	SVTR	2805S	SVTR	2812S	SVTR	2815S
+V _{OUT} (V)	R _{TRIM} (Ω)						
3.60	1.13k	5.50	1.05k	13.2	1.09k	16.5	1.09k
3.55	1.36k	5.45	1.18k	13.1	1.19k	16.4	1.18k
3.50	1.72k	5.40	1.33k	13.0	1.33k	16.3	1.28k
3.45	2.32k	5.35	1.54k	12.9	1.49k	16.2	1.40k
3.40	3.59k	5.30	1.82k	12.8	1.70k	16.1	1.54k
3.35	7.87k	5.25	2.22k	12.7	1.98k	16.0	1.71k
3.30	-	5.20	2.86k	12.6	2.38k	15.9	1.94k
		5.15	4.00k	12.5	2.96k	15.8	2.22k
		5.10	6.67k	12.4	3.94k	15.7	2.61k
		5.05	20.0k	12.3	5.86k	15.6	3.16k
		5.00	-	12.2	11.4k	15.5	4.00k
				12.1	242k	15.4	5.46k
				12.0	-	15.3	8.57k
						15.2	20.0k
						15.1	Note 1
						15.0	-

Notes: 1. Connect R-TRIM = 400Ω from +VOUT (PIN 5) to +S (PIN 6).



EFFICIENCY PERFORMANCE CURVES (T_{CASE} = 25°C, Full Load, Unless Otherwise Specified)

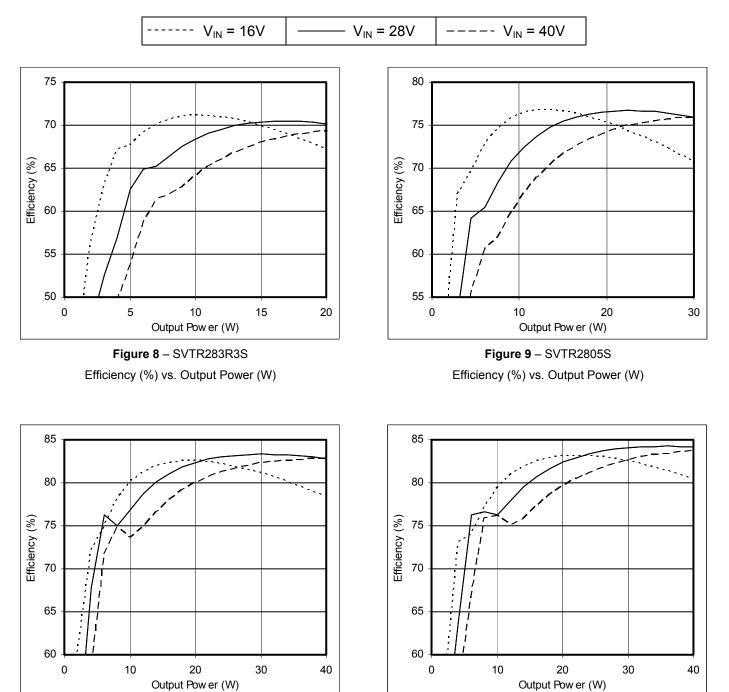
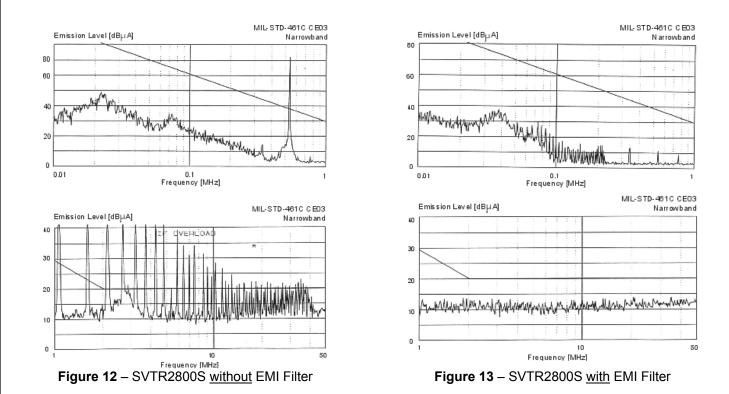


Figure 10 – SVTR2812S Efficiency (%) vs. Output Power (W)

Figure 11 – SVTR2815S Efficiency (%) vs. Output Power (W)



EMI PERFORMANCE CURVES (T_{CASE} = 25°C, V_{IN} = +28V ± 5%, Full Load, Unless Otherwise Specified)



RADIATION HARDNESS ASSURANCE (RHA)

The SVTR series radiation performance is guaranteed through the use of hardened semiconductor components, radiation lot acceptance testing (RLAT) of non-hardened components, and characterization of the completed hybrid according to VPT's Radiation Hardness Assurance (RHA) plan per MIL-PRF-38534, Appendix G. Post radiation end of life performance limits are determined by worst case analysis.

As part of qualification, one representative model of the hybrid converter family is characterized for total ionizing dose (TID). TID is tested to 60 krad(Si). Subsequent performance is guaranteed to 30 krad(Si) by 2 times margin. Characterization is performed at high dose rate (HDR) in accordance with condition C (minimum dose rate of 30 rad(Si)/s) of method 1019 of MIL-STD-883, and at low dose rate (LDR) in accordance with condition D of method 1019 of MIL-STD-883. A minimum of 1 biased sample and 1 unbiased sample is tested. After radiation exposure, converter testing is performed at 25 °C per standard datasheet limits. The radiation exposure test circuit is given in Figure 14.

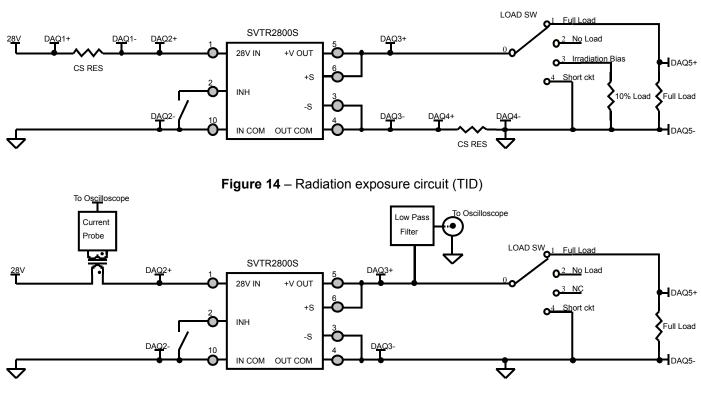
Also as part of qualification, one representative model of the hybrid converter family is characterized for Single Event Effects (SEE). The specific test LET is specified on the first page of the datasheet and is tested to a minimum fluence of 1×10^6 particles/cm². The characterization is performed at nominal input voltage at 25 °C in air. The radiation exposure test circuit is specified in Figure 15.

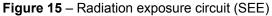


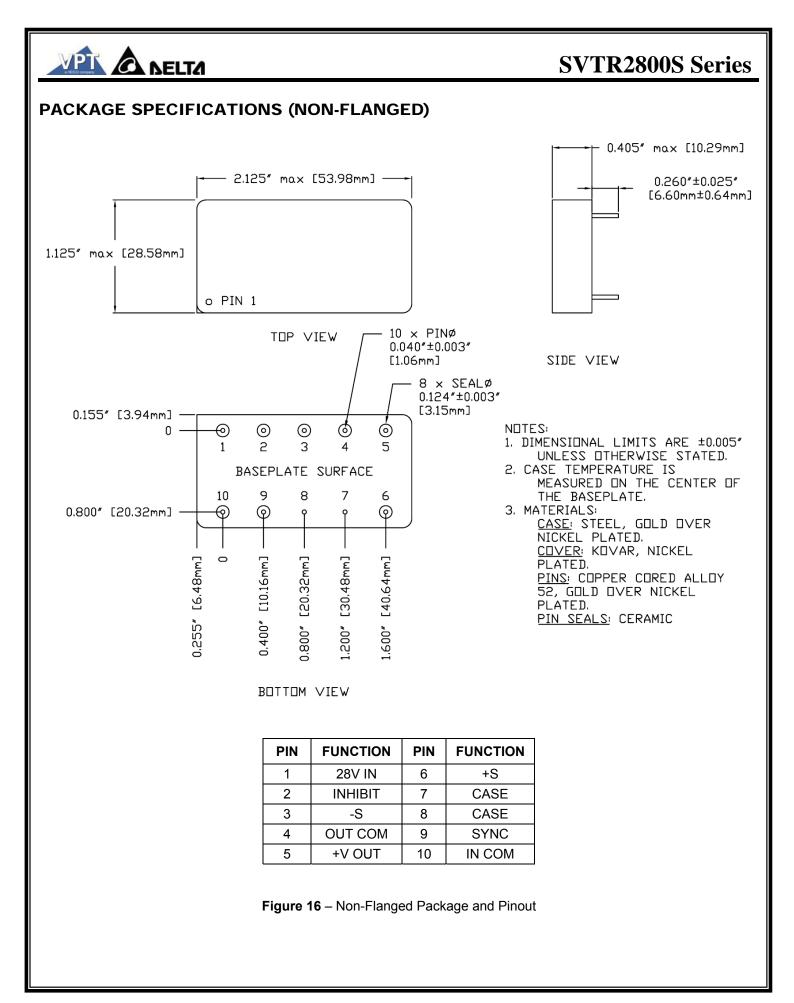
RADIATION HARDNESS ASSURANCE (continued)

Continued compliance is guaranteed by component testing and analysis. Critical semiconductor components, unless procured with manufacturer radiation guarantees, are subjected to RLAT at HDR in accordance with condition C of method 1019 of MIL-STD-883. Semiconductors which have been shown to exhibit ELDRS are subject to RLAT at LDR in accordance with condition D of method 1019 of MIL-STD-883. RLAT is not performed on inherently radiation hard semiconductor component technologies including zeners, diodes, and small signal BJTs.

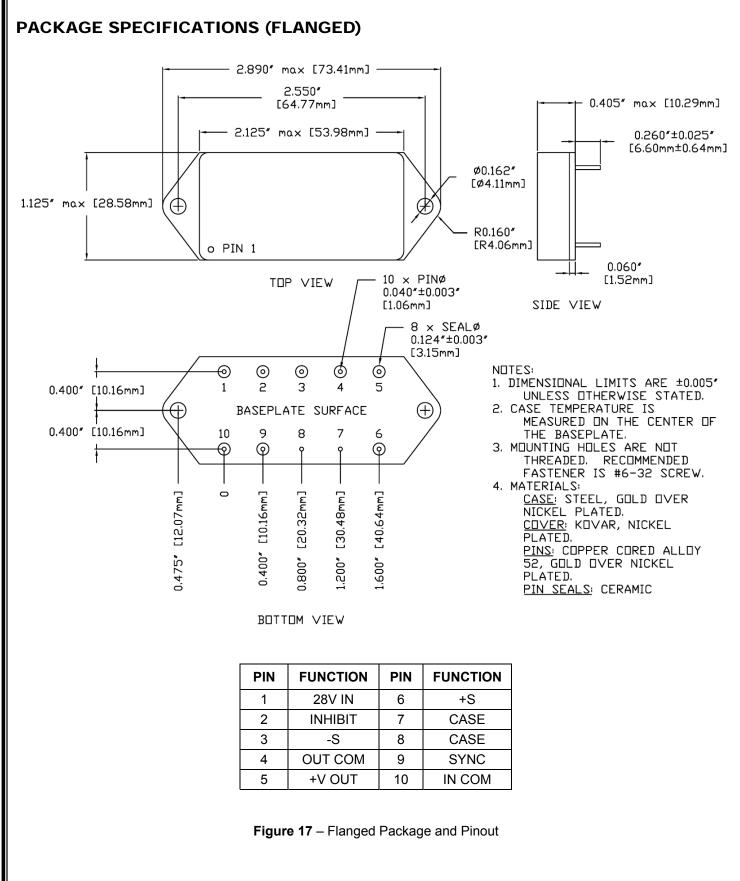
RHA TEST CIRCUIT DIAGRAMS













PACKAGE PIN DESCRIPTION

Pin	Function	Description
1	28V IN	Positive Input Voltage Connection
2	INHIBIT	Logic Low = Disabled Output. Connecting the inhibit pin to input common causes converter shutdown. Logic High = Enabled Output. Unconnected or open collector TTL.
3	-S	Return Sense
4	OUT COM	Output Common Connection
5	+V OUT	Positive Output Voltage Connection
6	+S	Positive Sense
7	CASE	Case Connection
8	CASE	Case Connection
9	SYNC	Synchronization Signal
10	IN COM	Input Common Connection



ENVIRONMENTAL SCREENING (100% Tested Per MIL-STD-883 as referenced to MIL-PRF-38534)

Screening	MIL-STD-883	Class H+ /H+	Class K /K	Engineering Model ⁵ /EM
Non-Destructive Bond Pull	Method 2023 ³	•	•	•
Internal Visual	Method 2017, 2032 Internal Procedure	•	•	•
Temperature Cycling	Method 1010, Condition C	•	•	
Constant Acceleration	Method 2001, 3000g, Y1 Direction	•	•	
PIND	Method 2020, Condition A ²	•	•	
Pre Burn-In Electrical	100% at 25°C		•	
Burn-In	Method 1015, 320 hours at +125°C Method 1015, 160 hours at +125°C 24 Hours at +125°C	•	•	•
Final Electrical	MIL-PRF-38534, Group A ¹ 100% at 25°C	•	•	•
Hermeticity	Method 1014, Fine Leak, Condition A Method 1014, Gross Leak, Condition C Dip (1×10^{-3})	•	•	•
Radiography	Method 2012 ⁶		•	
External Visual	Method 2009	•	•	•

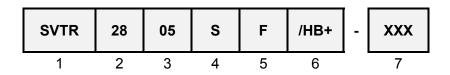
Notes:

1. 100% R&R testing at -55°C, +25°C, and +125°C with all test data included in product shipment.

- 2. PIND test Certificate of Compliance included in product shipment.
- 3. Non-Destructive bond pull per Method 2023 performed.
- 4. Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing options desired.
- 5. Engineering models utilize only the standard screening specified and are not considered compliant for flight use.
- 6. Radiographic test Certificate of Compliance and film(s) included in product shipment.



ORDERING INFORMATION



(1)	(2)		(3)		(4)	
Product Series	Nominal Input Voltage		Output Voltage		Number of Outputs	
SVTR	28	28 Volts	3R3 05 12 15	3.3 Volts 5 Volts 12 Volts 15 Volts	S	Single

(5)		(6)		(7)	
Package Option		Screening Code		Additional Screening Code	
None F	Non-Flanged Flanged	/EM /H+ /K	Engineering Model Class H+ Class K	Contact Sales	

Note: Engineering models utilize only the standard screening specified and are not considered compliant for flight use. These models are intended for low volume engineering characterization. The customer must place the following statement on each line item of their purchase order(s) for /EM units when ordering engineering models:

"(<u>Customer Name</u>) acknowledges that the /EM unit listed in this line item is not permitted for flight use and will be used for Engineering characterization only."

Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing, different input voltage, output voltage, power requirement, source inspection, and/or special element evaluation for space or other higher quality applications.



SMD (STANDARD MICROCIRCUIT DRAWING) NUMBERS

Standard Microcircuit	SVTR2800S Series
Drawing (SMD)	Similar Part Number
5962P1122001HXC	SVTR283R3S/H+
5962P1122001HYC	SVTR283R3SF/H+
5962P1122001KXC	SVTR283R3S/K
5962P1122001KYC	SVTR283R3SF/K
5962P1122002HXC	SVTR2805S/H+
5962P1122002HYC	SVTR2805SF/H+
5962P1122002KXC	SVTR2805S/K
5962P1122002KXC	SVTR2805SF/K
5962P1122003HXC	SVTR2812S/H+
5962P1122003HYC	SVTR2812SF/H+
5962P1122003KXC	SVTR2812S/K
5962P1122003KYC	SVTR2812SF/K
5962P1122004HXC	SVTR2815S/H+
5962P1122004HYC	SVTR2815SF/H+
5962P1122004KXC	SVTR2815S/K
5962P1122004KYC	SVTR2815SF/K

Do not use the SVTR2800S Series similar part number for SMD product acquisition. It is listed for reference only. For exact specifications for the SMD product, refer to the SMD drawing. SMDs can be downloaded from the DLA Land and Maritime (Previously known as DSCC) website at http://www.dscc.dla.mil/programs/smcr/. The SMD number listed above is for standard gold-plated lead finish and "P" RHA (Radiation Hardness Assurance) level. Please reference the SMD for other screening levels, lead finishes, and radiation levels. All SMD products are marked with a "Q" on the cover as specified by the QML certification mark requirement of MIL-PRF-38534.

CONTACT INFORMATION

To request a quotation or place orders please contact your sales representative or the VPT Inc. Sales Department at:

Phone:	(425) 353-3010
Fax:	(425) 353-4030
E-mail:	vptsales@vpt-inc.com

All information contained in this datasheet is believed to be accurate, however, no responsibility is assumed for possible errors or omissions. The products or specifications contained herein are subject to change without notice.